

MOS FIELD EFFECT TRANSISTOR **2SK3458**

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3458 is N-channel DMOS FET device that features a low gate charge and excellent switching characteristics, designed for high voltage applications such as switching power supply.

ORDERING INF	ORMATION
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PART NUMBER	PACKAGE		
2SK3458	TO-220AB		
2SK3458-S	TO-262		
2SK3458-ZK	TO-263		

FEATURES

Low gate charge

 $Q_G = 25 \text{ nC TYP}$. (VDD = 450 V, VGS = 10 V, ID = 6.0 A)

- Gate voltage rating ±30 V
- Low on-state resistance

 $R_{DS(on)} = 2.2 \ \Omega MAX. (V_{GS} = 10 \ V, I_{D} = 3.0 \ A)$

- Avalanche capability ratings
- Surface mount package available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	800	V
Gate to Source Voltage ($V_{DS} = 0 V$)	Vgss	±30	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±6.0	А
Drain Current (pulse) Note1	D(pulse)	±24	А
Total Power Dissipation (T _A = 25°C)	PT1	1.5	W
Total Power Dissipation (Tc = 25°C)	Рт2	100	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	6.0	А
Single Avalanche Energy Note2	Eas	66.5	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 150 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

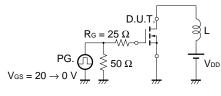
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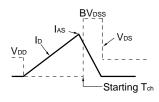
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vds = 800 V, Vgs = 0 V			100	μA
Gate Leakage Current	Igss	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA
Gate Cut-off Voltage	VGS(off)	V _{DS} = 10 V, I _D = 1 mA	2.5		3.5	V
Forward Transfer Admittance	y _{fs}	VDS = 10 V, ID = 3.0 A	2.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Id = 3.0 A		1.8	2.2	Ω
Input Capacitance	Ciss	V _{DS} = 10 V		1220		pF
Output Capacitance	Coss	Vgs = 0 V		170		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		16		pF
Turn-on Delay Time	td(on)	V _{DD} = 150 V, I _D = 3.0 A		17		ns
Rise Time	tr	Vgs = 10 V		7		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		43		ns
Fall Time	tr			11		ns
Total Gate Charge	QG	V _{DD} = 450 V		25		nC
Gate to Source Charge	QGS	Vgs = 10 V		6		nC
Gate to Drain Charge	Qgd	ID = 6.0 A		10		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 6.0 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 6.0 A, VGS = 0 V		1490		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ μs		7.5		μC

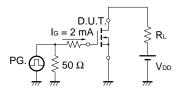
TEST CIRCUIT 1 AVALANCHE CAPABILITY

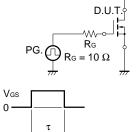
TEST CIRCUIT 2 SWITCHING TIME



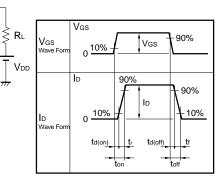


TEST CIRCUIT 3 GATE CHARGE



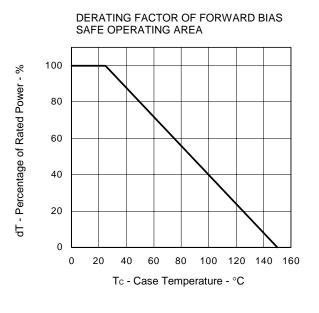


 $\tau = 1 \ \mu s$ Duty Cycle $\leq 1\%$

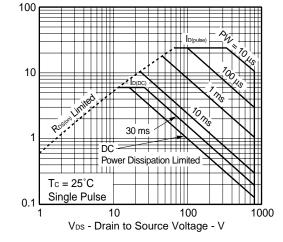


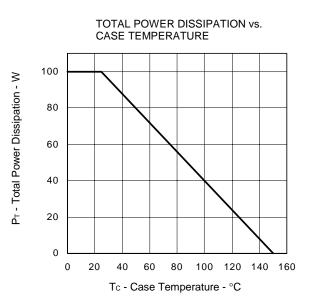
lo - Drain Current - A

TYPICAL CHARACTERISTICS (TA = 25°C)

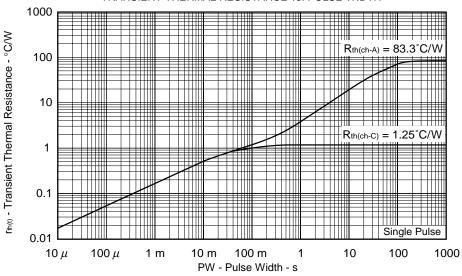




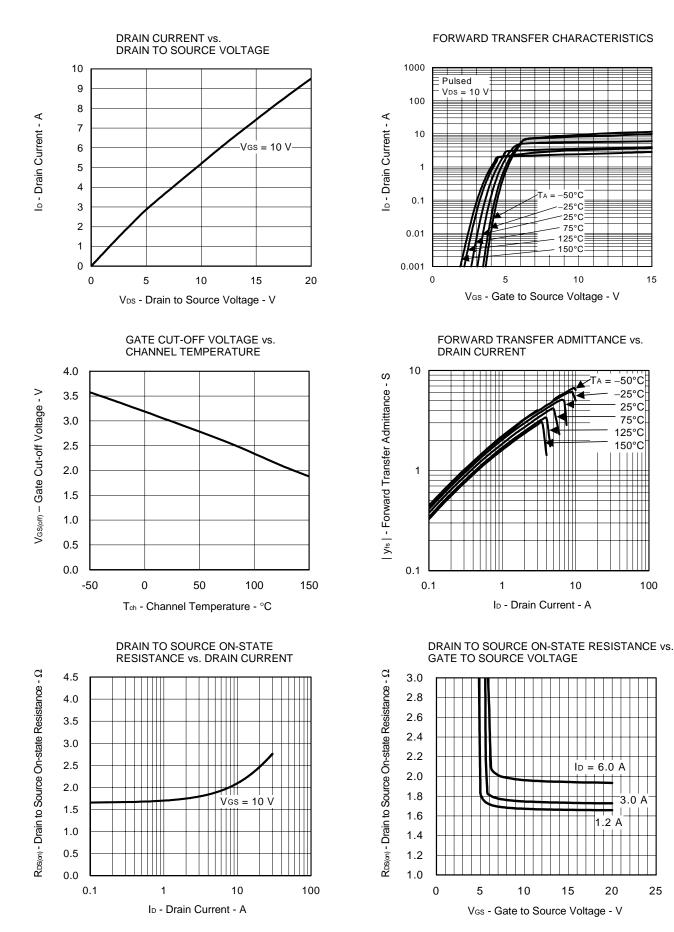




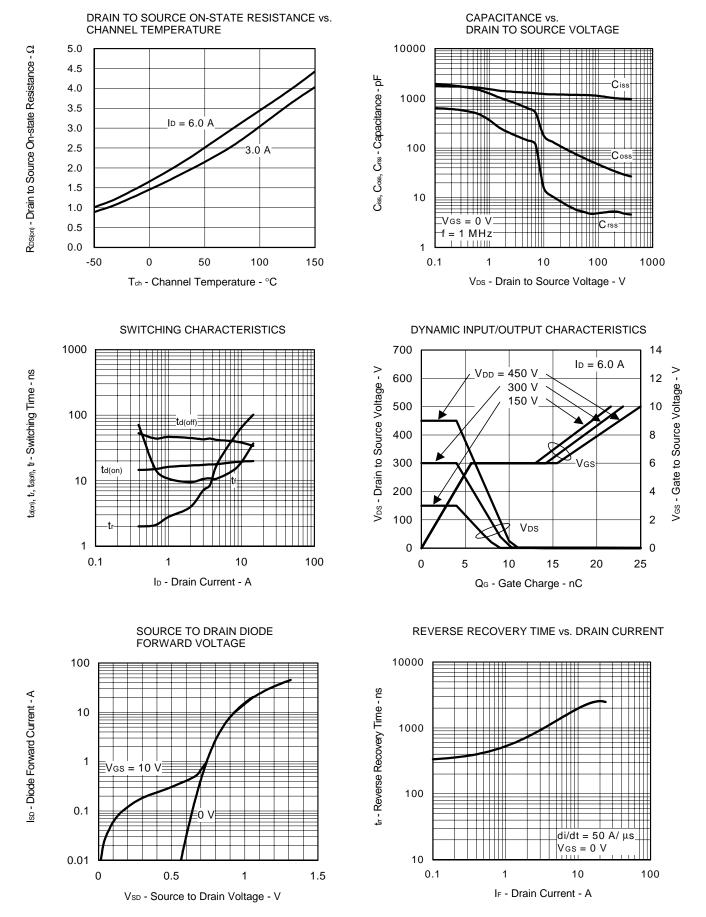
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



Data Sheet D14755EJ1V0DS

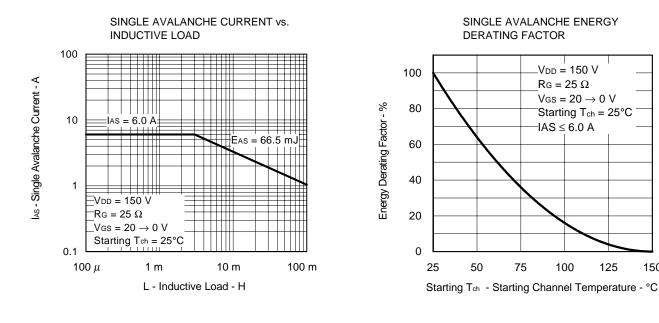


Data Sheet D14755EJ1V0DS



Data Sheet D14755EJ1V0DS

150



<u>1.3±</u>0.2

2.8±0.2

4.8 MAX.

0.5±0.2

1.Gate

2.Drain

3.Source

4.Fin (Drain)

E

2) TO-262 (MP-25 Fin Cut)

1 2 3

4

1.3±0.2

<u>.75±0.3</u> .54 TYF 10 TYP

1.0±0.5

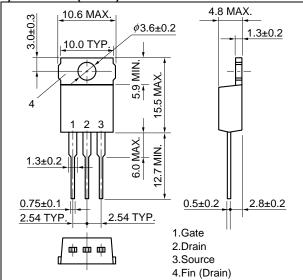
8.5±0.2

12.7 MIN.

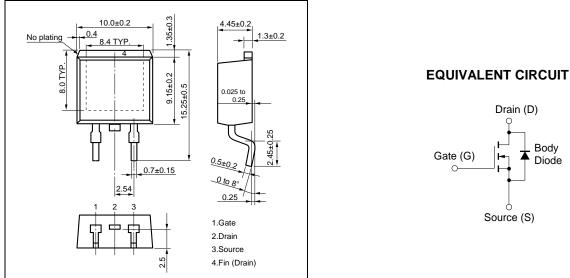
2.54 TYP.

PACKAGE DRAWINGS (Unit: mm)

1) TO-220AB (MP-25)



3) TO-263 (MP-25ZK)



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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